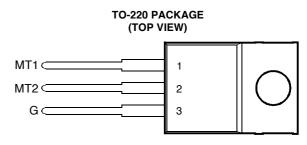
# **BOURNS®**

- High Current Triacs
- 12 A RMS
- Glass Passivated Wafer
- 400 V to 800 V Off-State Voltage
- Max I<sub>GT</sub> of 50 mA (Quadrants 1 3)



Pin 2 is in electrical contact with the mounting base.

MDC2ACA



# absolute maximum ratings over operating case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	TIC236D		400	
Repetitive peak off-state voltage (see Note 1)	TIC236M	M	600	V
	TIC236S	$V_{DRM}$	700	V
	TIC236N		800	
Full-cycle RMS on-state current at (or below) 70°C case temperature (see Note 2)			12	Α
Peak on-state surge current full-sine-wave at (or below) 25°C case temperature (see Note 3)			100	Α
Peak gate current			±1	Α
Operating case temperature range			-40 to +110	°C
Storage temperature range			-40 to +125	°C
Lead temperature 1.6 mm from case for 10 seconds			230	°C

- NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.
  - 2. This value applies for 50-Hz full-sine-wave operation with resistive load. Above 70°C derate linearly to 110°C case temperature at the rate of 300 mA/°C.
  - 3. This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of peak reverse volta ge and on-state current. Surge may be repeated after the device has returned to original thermal equilibrium.

## electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
I <sub>DRM</sub>	Repetitive peak off-state current	V <sub>D</sub> = Rated V <sub>DRM</sub>	I <sub>G</sub> = 0	T <sub>C</sub> = 110°C			±2	mA
I <sub>GT</sub>		V <sub>supply</sub> = +12 V†	$R_L = 10 \Omega$	t <sub>p(g)</sub> > 20 μs		12	50	mA
	Gate trigger	$V_{\text{supply}} = +12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		-19	-50	
	current	$V_{\text{supply}} = -12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		-16	-50	ША
		$V_{\text{supply}} = -12 \text{ V}^{\dagger}$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		34		
V <sub>GT</sub>		$V_{\text{supply}} = +12 \text{ V}\dagger$	$R_L = 10 \Omega$	t <sub>p(g)</sub> > 20 μs		8.0	2	V
	Gate trigger	$V_{\text{supply}} = +12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		-0.8	-2	
	voltage	$V_{\text{supply}} = -12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		-0.8	-2	
		$V_{\text{supply}} = -12 \text{ V}\dagger$	$R_L = 10 \Omega$	$t_{p(g)} > 20 \mu s$		0.9	2	
V <sub>T</sub>	On-state voltage	I <sub>TM</sub> = ±17 A	$I_G = 50 \text{ mA}$	(see Note 4)		±1.4	±2.1	V

<sup>†</sup> All voltages are with respect to Main Terminal 1.

NOTE 4: This parameter must be measured using pulse techniques, t<sub>p</sub> = < 1 ms, duty cycle < 2 %. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.

## PRODUCT INFORMATION



# electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

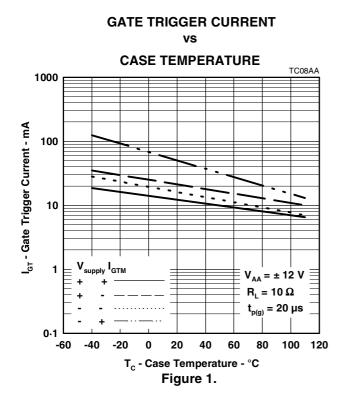
	PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
1	Holding current	V <sub>supply</sub> = +12 V†	I <sub>G</sub> = 0	Init' I <sub>TM</sub> = 100 mA		22	40	mA
Ή	riolaling current	$V_{\text{supply}} = -12 \text{ V}^{\dagger}$	$I_G = 0$	Init' $I_{TM} = -100 \text{ mA}$		-12	-40	ША
IL	Latching current	$V_{\text{supply}} = +12 \text{ V}^{\dagger}$	(see Note 5)			80	mA	
		$V_{\text{supply}} = -12 \text{ V}^{\dagger}$					-80	ША
dv/dt	Critical rate of rise of	V <sub>D</sub> = Rated V <sub>D</sub>	I <sub>G</sub> = 0	T <sub>C</sub> = 110°C		±400		V/µs
	off-state voltage					±400		ν/μ5
dv/dt <sub>(c)</sub>	Critical rise of	$V_D = Rated V_D$		$T_C = 80^{\circ}C$	±1.2	±9		V/µs
	commutation voltage	$di/dt = 0.5 I_{T(RMS)}/ms$		$I_T = 1.4 I_{T(RMS)}$		±3		ν/μδ
di/dt	Critical rate of rise of	$V_D = Rated V_D$	I <sub>GT</sub> = 50 mA	T <sub>C</sub> = 110°C		±100		A/µs
	on -state current	di <sub>G</sub> /dt = 50 mA/μs				±100		-Α/μδ

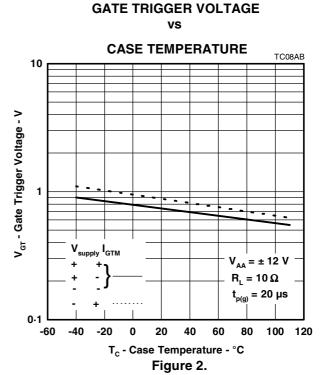
<sup>†</sup> All voltages are with respect to Main Terminal 1.

#### thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

#### **TYPICAL CHARACTERISTICS**





### PRODUCT INFORMATION

NOTE 5: The triacs are triggered by a 15-V (open-circuit amplitude) pulse supplied by a generator with the following characteristics:  $R_G = 100 \ \Omega$ ,  $t_{p(g)} = 20 \ \mu s$ ,  $t_r = \le 15 \ ns$ ,  $f = 1 \ kHz$ .

## **TYPICAL CHARACTERISTICS**

